

SPECIFICATION

- Supplier : Samsung electro-mechanics
- Product : Multi-layer Ceramic Capacitor
- Samsung P/N : **CL03A104KQ3NNNC**
- Description : **CAP, 100nF, 6.3V, ±10%, X5R, 0201**

A. Samsung Part Number

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① Series	Samsung Multi-layer Ceramic Capacitor		
② Size	0201 (inch code)	L: 0.6 ± 0.03 mm	W: 0.3 ± 0.03 mm
③ Dielectric	X5R	⑧ Inner electrode Termination	Ni Cu
④ Capacitance	100 nF	Plating	Sn 100% (Pb Free)
⑤ Capacitance tolerance	±10 %	⑨ Product	Normal
⑥ Rated Voltage	6.3 V	⑩ Special	Reserved for future use
⑦ Thickness	0.3 ± 0.03 mm	⑪ Packaging	Cardboard Type, 7" reel

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms
Tan δ (DF)	0.1 max.	
Insulation Resistance	10,000Mohm or 100Mohm·μF Whichever is Smaller	Rated Voltage 60~120 sec.
Appearance	No abnormal exterior appearance	Microscope (×10)
Withstanding Voltage	No dielectric breakdown or mechanical breakdown	250% of the rated voltage
Temperature Characterisitcs	X5R (From -55℃ to 85℃, Capacitance change should be within ±15%)	
Adhesive Strength of Termination	No peeling shall be occur on the terminal electrode	200g·F, for 10±1 sec.
Bending Strength	Capacitance change : within ±12.5%	Bending to the limit (1mm) with 1.0mm/sec.
Solderability	More than 75% of terminal surface is to be soldered newly	1) Sn63Pb37 solder 235±5℃, 5±0.5sec. 2) SnAg3.0Cu0.5 solder 245±5℃, 3±0.3sec. (preheating : 80~120℃ for 10~30sec.)
Resistance to Soldering heat	Capacitance change : within ±7.5% Tan δ, IR : initial spec.	Solder pot : 270±5℃, 10±1sec.

	Performance	Test condition
Vibration Test	Capacitance change : within $\pm 5\%$ Tan δ , IR : initial spec.	Amplitude : 1.5mm From 10Hz to 55Hz (return : 1min.) 2hours \times 3 direction (x, y, z)
Humidity	Capacitance change : within $\pm 12.5\%$ Tan δ : 0.125 max IR : $25M\Omega \cdot \mu F$ or Over	$40 \pm 2^\circ C$, 90~95%RH, 500+12/-0hrs
Moisture Resistance	Capacitance change : within $\pm 12.5\%$ Tan δ : 0.125 max IR : $12.5M\Omega \cdot \mu F$ or Over	With rated voltage $40 \pm 2^\circ C$, 90~95%RH, 500+12/-0hrs
High Temperature Resistance	Capacitance change : within $\pm 12.5\%$ Tan δ : 0.125 max IR : $25M\Omega \cdot \mu F$ or Over	With 100% of the rated voltage Max. operating temperature 1000+48/-0hrs
Temperature Cycling	Capacitance change : within $\pm 7.5\%$ Tan δ , IR : initial spec.	1 cycle condition Min. operating temperature $\rightarrow 25^\circ C$ \rightarrow Max. operating temperature $\rightarrow 25^\circ C$ 5 cycle test

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : $260 \pm 0/-5^\circ C$, 10sec. Max)

* For the more detail Specification, Please refer to the Samsung MLCC catalogue.